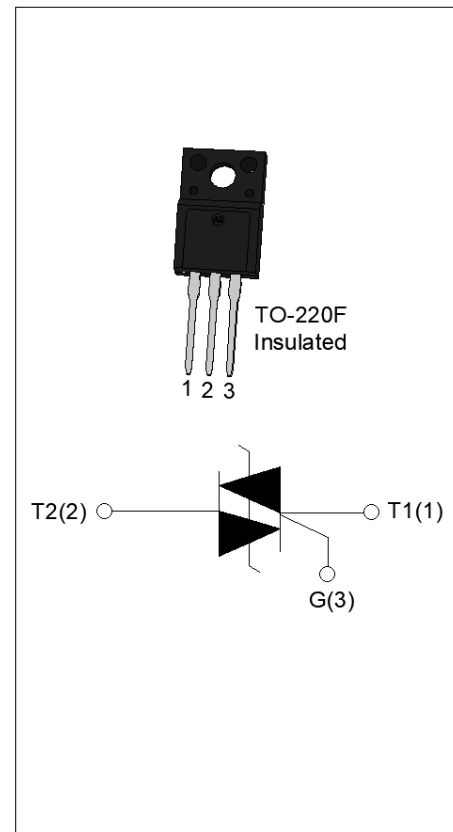


**ACJT610-10F 6A TRIAC**

Rev.A.1.0

**DESCRIPTION:**

The ACJT610-10F triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. The ACJT610-10F embeds a TVS structure to absorb the inductive turn-off energy such as those described in the IEC 61000-4-5 standards. By using an external plastic package, ACJT610-10F provides a rated insulation voltage of 2000 VRMS. Package TO-220F is RoHS compliant.


**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	6	A
$V_{DRM}/V_{RRM}$	1000	V
$I_{GT} / /$	10/10/10	mA

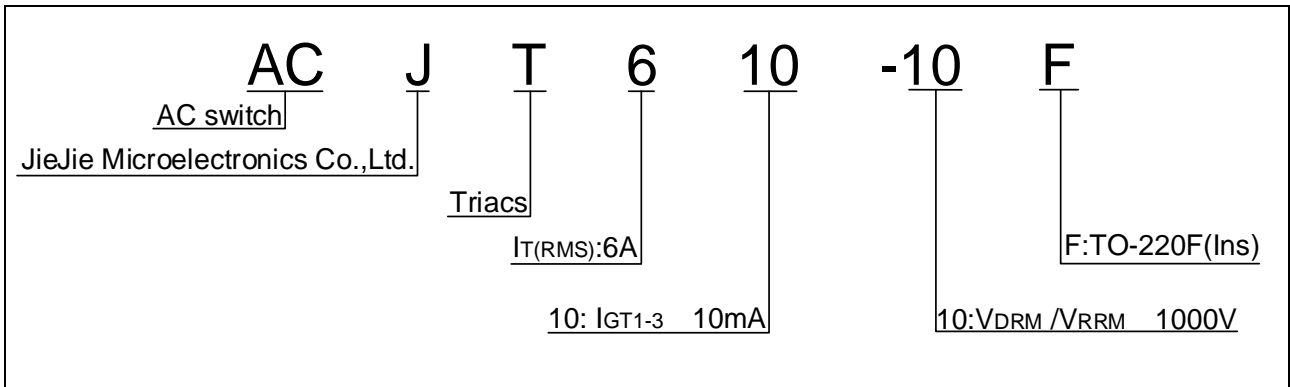
**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )	$V_{DRM}$	1000	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )	$V_{RRM}$	1000	V
RMS on-state current ( $T_c = 98^\circ\text{C}$ )	$I_{T(RMS)}$	6	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I_{TSM}$	60	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$ , $T_j=25^\circ\text{C}$ )		66	
$I^2t$ value for fusing ( $t_p=10\text{ms}$ , $T_j=25^\circ\text{C}$ )	$I^2t$	18	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100\text{Hz}$ , $T_j=125^\circ\text{C}$ )	$di/dt$	100	$\text{A/s}$
Peak gate current ( $t_p=20\text{ }\mu\text{s}$ , $T_j=125^\circ\text{C}$ )	$I_{GM}$	4	A

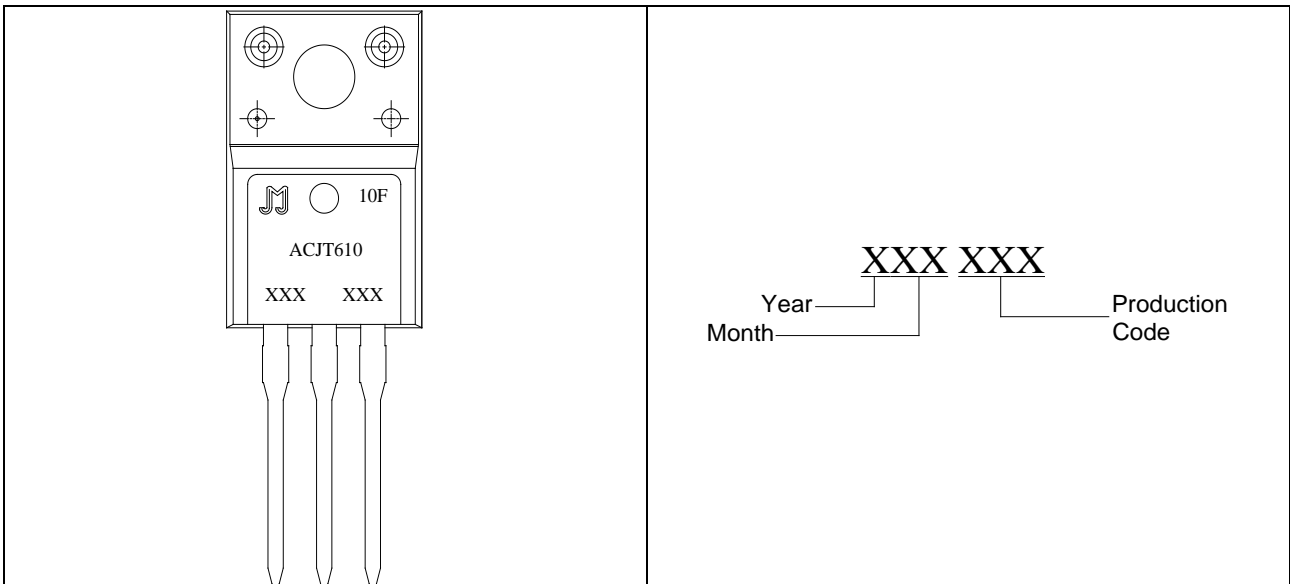
# ACJT610-10F

Average gate power dissipation ( $T_j=125$ )	$P_{G(AV)}$	0.5	W
Peak gate power	$P_{GM}$	10	W
Peak pulse voltage			

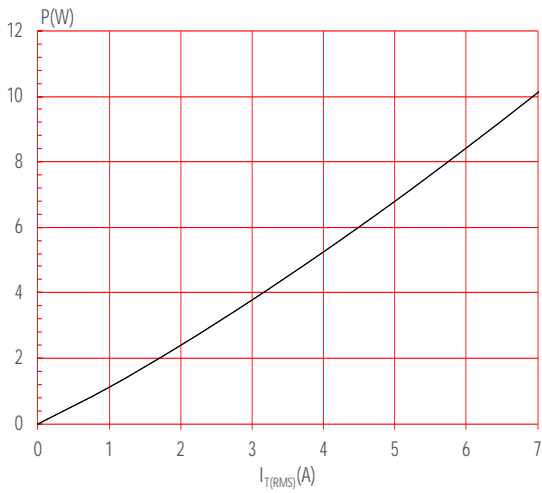
ORDERING INFORMATION



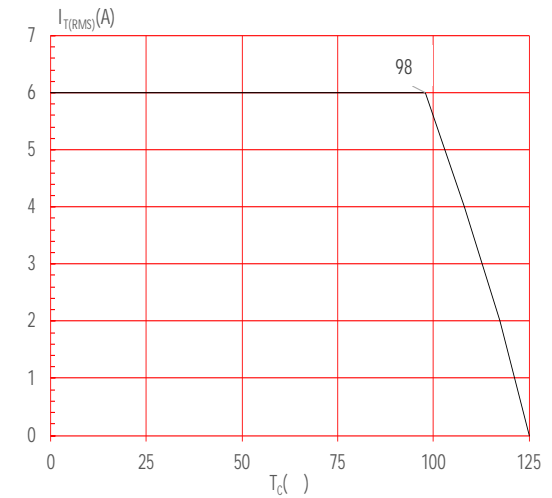
MARKING



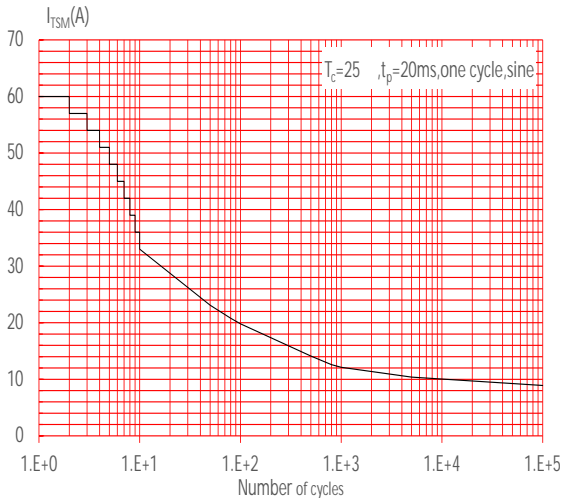
**FIG.1** Maximum power dissipation versus RMS on-state current



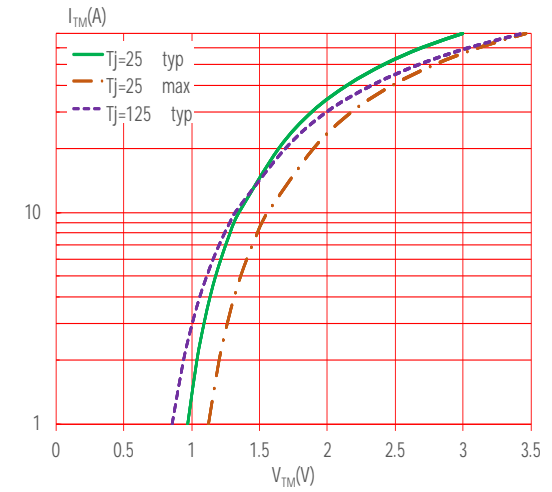
**FIG.2:** RMS on-state current versus case temperature



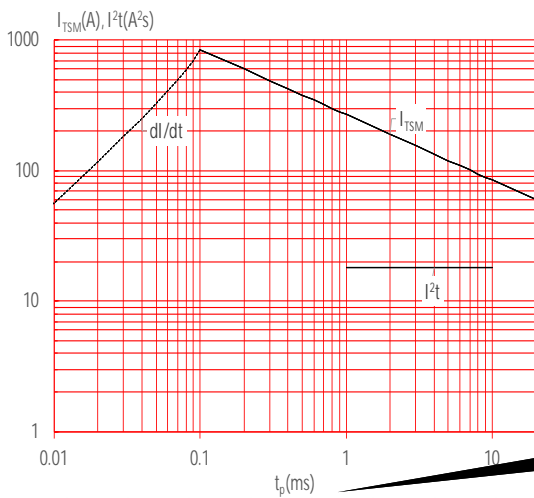
**FIG.3:** Surge peak on-state current versus number of cycles



**FIG.4:** On-state characteristics



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

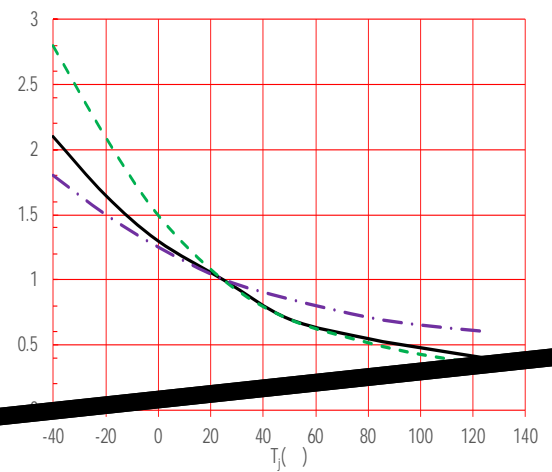
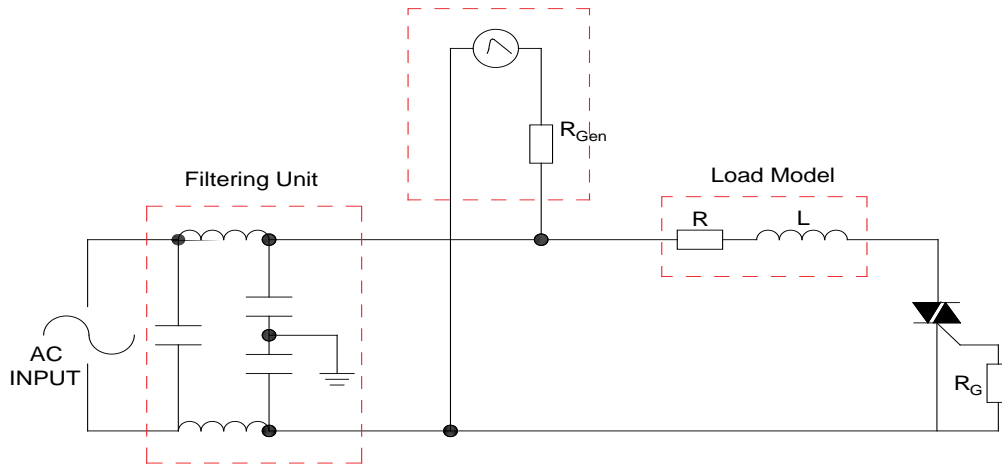


FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards  
IEC61000-4-5 Standards  
Surge Generator



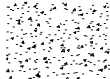
**ORDERING INFORMATION**

<b>Order code</b>	<b>Voltage <math>V_{DRM}/V_{RRM}</math> (V)</b>	<b>IGT(mA)</b>	<b>Package</b>	<b>Base qty. (pcs)</b>	<b>Delivery mode</b>
<b>ACJT610-10F</b>	<b>1000</b>	<b>10</b>	<b>TO-220F(Ins)</b>	<b>50</b>	<b>Tube</b>

**Document Revision History**


<b>Date</b>	<b>Revision</b>	<b>Changes</b>
Apr.14, 2023	A.1.0	Last updated

**PACKAGE MECHANICAL DATA**



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